

2SD1472

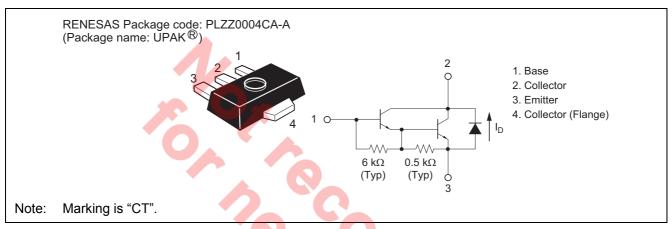
Silicon NPN Epitaxial, Darlington

REJ03G0792-0300 Rev.3.00 Nov 30, 2007

Application

Low frequency power amplifier

Outline



*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit V	
Collector to base voltage	V _{CBO}	120		
Collector to emitter voltage	V _{CEO}	120	V	
Emitter to base voltage	V _{EBO}	7	V	
Collector current	Ic	1.5	A	
Collector peak current	i _{C(peak)} *1	3.0	A	
Collector power dissipation	P _C * ²	1.0	W	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	
E to C diode forward current	I _D	1.5	A	

Notes: 1. Pulse ≤ 10 ms, Duty cycle ≤ 20%

2. Value on the alumina ceramic board (12.5 x 30 x 0.7 mm)

Electrical Characteristics

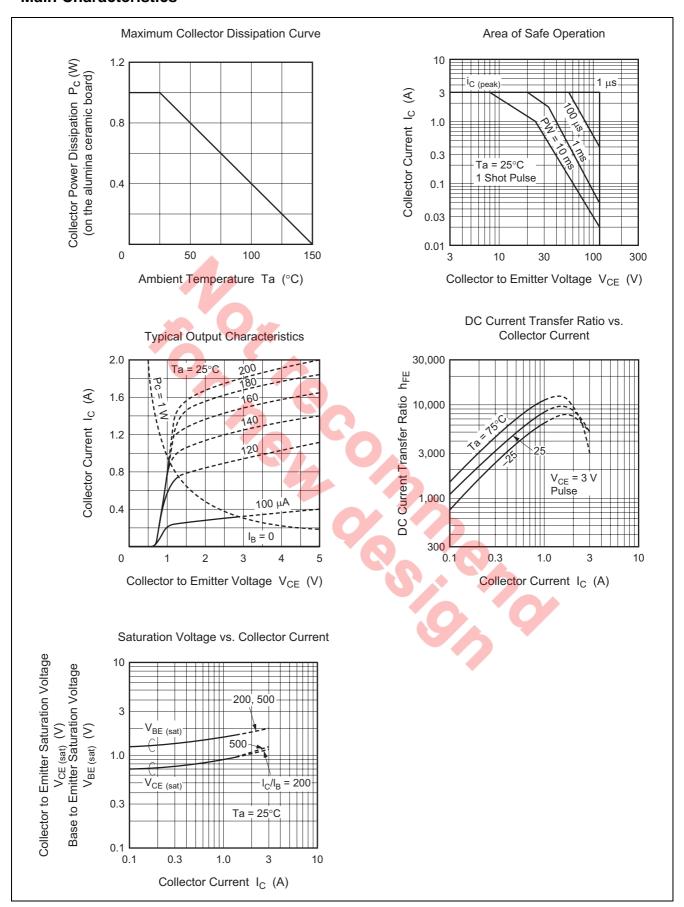
 $(Ta = 25^{\circ}C)$

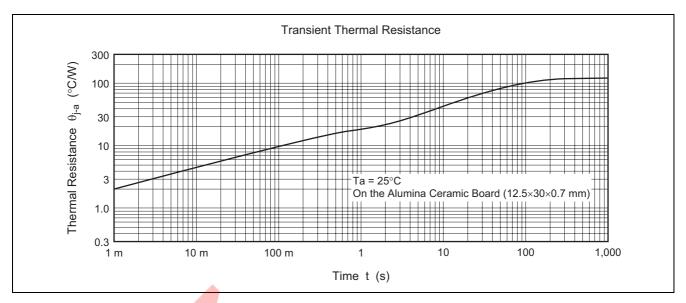
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	120	_	_	V	$I_C = 0.1 \text{ mA}, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	120	_	_	٧	I_C = 10 mA, R_{BE} = ∞
Emitter to base breakdown voltage	$V_{(BR)EBO}$	7	-	_	V	$I_E = 50 \text{ mA}, I_C = 0$
Collector cutoff current	I _{CBO}	_		1.0	μΑ	V _{CB} = 100 V, I _E = 0
	I _{CEO}	_	1	10		V _{CE} = 100 V, R _{BE} = ∞
DC current transfer ratio	h_FE	2000	1	30000		$V_{CE} = 3 \text{ V}, I_{C} = 1 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{\text{CE}(\text{sat})1}$	_	1	1.5	>	$I_C = 1 \text{ A}, I_B = 1 \text{ mA*}^1$
	$V_{CE(sat)2}$	_	_	2.0	V	$I_C = 1.5 \text{ A}, I_B = 1.5 \text{ mA*}^1$
Base to emitter saturation voltage	$V_{BE(sat)1}$	_	1	2.0	>	$I_C = 1 \text{ A}, I_B = 1 \text{ mA*}^1$
	$V_{BE(sat)2}$	_	_	2.5	V	$I_C = 1.5 \text{ A}, I_B = 1.5 \text{ mA*}^1$
E to C diode forward voltage	V_D	_	_	3.0	V	I _D = 1.5 A* ¹

Notes: 1. Pulse test



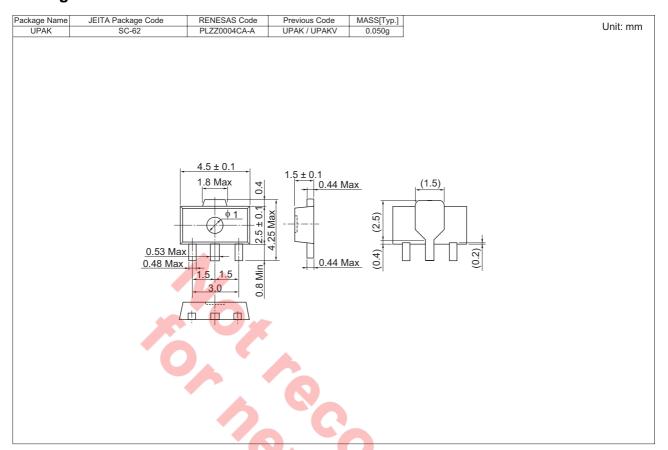
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SD1472CTTR-E	1000	φ 178 mm Reel, 12 mm Emboss Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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